

SOT-227 Silicon Carbide Schottky Barrier Diode, 1200 V, 200 A



PRIMARY CHARACTERISTICS						
V _R	1200 V					
V _F (typical) at 100 A, per diode	1.45 V					
Q _C (typical), per diode	553 nC					
I _{F(DC)} per module at T _C = 130 °C	200 A					
Type	Modules - diode, SiC Schottky					
Package	SOT-227					
Circuit configuration	Two separate diodes, parallel pin-out					

FEATURES

Virtually no recovery tail and no switching losses



 Majority carrier diode using Schottky technology on SiC wide band gap material RoHS COMPLIANT

- Improved V_F and efficiency by thin wafer technology
- High speed switching, low switching losses
- · Positive temperature coefficient, for easy paralleling
- · Electrically isolated base plate
- · Large creepage distance between terminal
- · Simplified mechanical designs, rapid assembly
- Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Wide band gap SiC based 1200 V Schottky diode, designed for high performance and ruggedness.

Optimum choice for high speed hard switching and efficient operation over a wide temperature range, it is also recommended for all applications suffering from Silicon ultrafast recovery behavior.

Typical applications include AC/DC PFC and DC/DC ultra high frequency output rectification in FBPS and LLC converters

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V_{R}		1200	V	
Continuous forward current per diode	I _F	T _C = 130 °C	100	۸	
Single pulse forward current per diode	I _{FSM}	T _J = 25 °C, 6 ms square pulse	620	А	
Maximum power dissipation per module	P_{D}	T _C = 130 °C	409	W	
RMS isolation voltage	V_{ISOL}	Any terminal to case, t = 1 min	2500	V	
Operating junction and storage temperature range	T_J, T_{Stg}		-55 to +175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	I _R = 100 μA	1200	-	-	
Forward voltage	V _{FM}	I _F = 100 A	-	1.45	1.61	V
		I _F = 100 A, T _J = 150 °C	-	1.86	-	
		V _R = 1200 V	-	6.85	300	
Reverse leakage current	I _{RM}	T _J = 125 °C, V _R = 1200 V	-	23.81	-	μA
		T _J = 150 °C, V _R = 1200 V	-	34.66	-	
Junction capacitance	C _T	V _R = 1200 V, f = 1 MHz	-	342	-	pF



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Total capacitive charge	Q _C	V _R = 800 V	-	553	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance junction to case, per diode	D		-	-	0.21	
Thermal resistance junction to case, per module	R _{thJC}		-	-	0.11	°C/W
Thermal resistance case to heatsink, per module	R _{thCS}	Flat, greased surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque		Torque per diode	-	-	1.1 (9.7)	Nm (lbf.in)
		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)
Case style				SOT	-227	

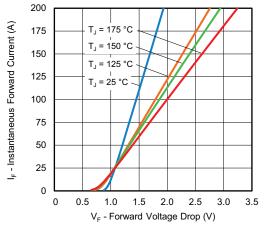


Fig. 1 - Typical Forward Voltage Drop Characteristics

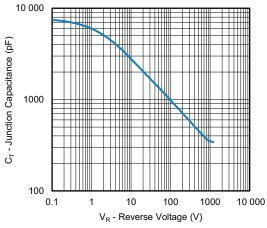


Fig. 3 - Junction Capacitance vs. Reverse Voltage

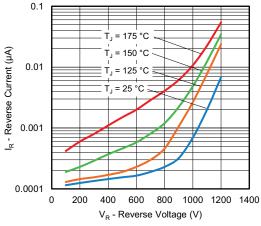


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

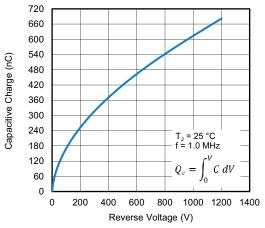


Fig. 4 - Typical Capacitive Charge vs. Reverse Voltage

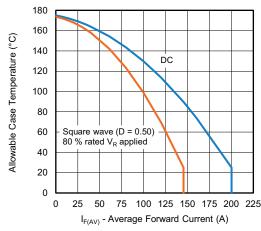


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

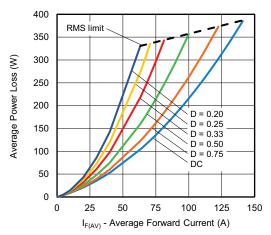


Fig. 6 - Forward Power Loss Characteristics

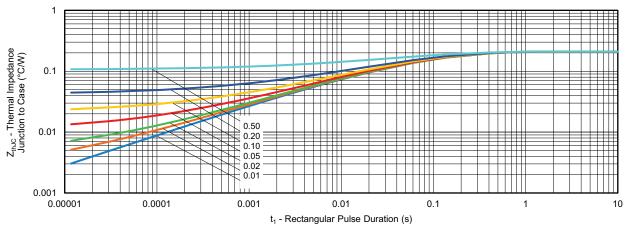


Fig. 7 - Maximum Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

1 - Vishay Semiconductors product

SC = SiC Schottky Barrier Diode

Current rating per module (200 = 200 A)

- F = circuit configuration (two separate diodes, parallel pin-out)

5 - Package indicator (SOT-227 standard insulated base)

Voltage rating (120 = 1200 V)

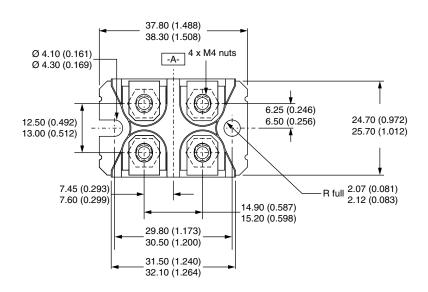


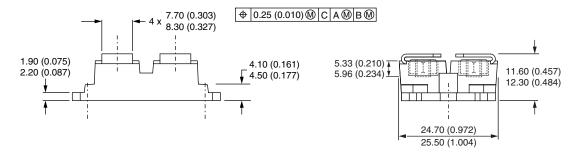
CIRCUIT CONFIC	CIRCUIT CONFIGURATION					
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
Two separate diodes, parallel pin-out	F	Lead Assignment 4 0 0 3 4 1 0 0 2 1				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95423				
Packaging information	www.vishay.com/doc?95425				

SOT-227 Generation 2

DIMENSIONS in millimeters (inches)





Note

· Controlling dimension: millimeter



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Vishay

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